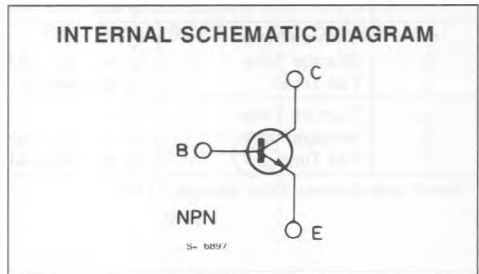
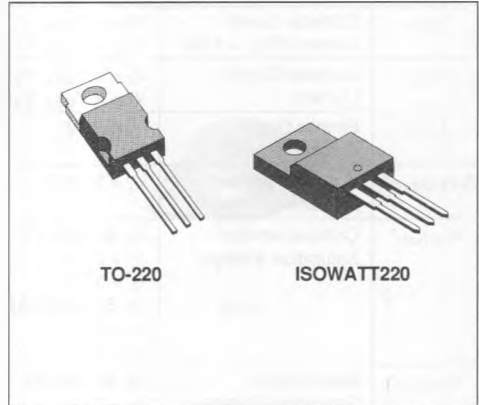




HIGH VOLTAGE POWER SWITCH

DESCRIPTION

The BUV46/A and BUV46FI/AFI are silicon multi-epitaxial mesa NPN transistors in the jedec TO-220 plastic package and ISOWATT220 fully isolated package respectively, intended for high voltage, fast switching applications.



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	TO-220 ISOWATT220	BUV46 BUV46FI	BUV46A BUV46AFI	Unit
V_{CES}	Collector-emitter Voltage ($V_{BE} = 0$)		850	1000	V
V_{CEX}	Collector-emitter Voltage ($V_{BE} = -2.5V$)		850	1000	V
V_{CEO}	Collector-emitter Voltage ($I_B = 0$)		400	450	V
V_{EBO}	Emitter-base Voltage ($I_C = 0$)		7		V
I_C	Collector Current		5		A
I_B	Base Current		3		A
			TO-220	ISOWATT220	
P_{Tot}	Total Power Dissipation at $T_c < 25^\circ C$		70	30	W
T_{sig}	Storage Temperature		- 65 to 150		$^\circ C$
T_j	Max. Operating Junction Temperature		150		$^\circ C$

THERMAL DATA

			TO-220	ISOWATT220	
$R_{th(j-case)}$	Thermal Resistance Junction-case	max	1.76	4.12	°C/W

ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CER}	Collector Cutoff Current ($R_{BE} = 10\Omega$)	$V_{CE} = V_{CEX}$			0.1	mA
		$V_{CE} = V_{CEX} T_c = 125^{\circ}C$			1	mA
I_{CEX}	Collector Cutoff Current	$V_{CE} = V_{CEX} V_{BE} = -2.5V$			0.3	mA
		$V_{CE} = V_{CEX} V_{BE} = -2.5V T_c = 125^{\circ}C$			2	mA
I_{EBO}	Emitter Cutoff Current ($I_C = 0$)	$V_{EB} = 7V$			1	mA
$V_{CEO(sus)}^*$	Collector-emitter Sustaining Voltage	$I_C = 100mA$				V
		for BUV46/FI for BUV46A/AFI	400 450			V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	for BUV46/FI				
		$I_C = 2.5A$ $I_B = 0.5A$			1.5	V
		$I_C = 3.5A$ $I_B = 0.7A$			5	V
		for BUV46A/AFI				
		$I_C = 2A$ $I_B = 0.4A$			1.5	V
		$I_C = 3A$ $I_B = 0.6A$			5	V
$V_{BE(sat)}^*$	Base-emitter Saturation Voltage	for BUV46/FI				
		$I_C = 2.5A$ $I_B = 0.5A$			1.3	V
		for BUV46A/AFI				
		$I_C = 2A$ $I_B = 0.4A$			1.3	V
t_{on} t_s t_f	Turn-on Time Storage Time Fall Time	$I_C = 2.5A$ $V_{CC} = 150V$			1	μs
		$I_{B1} = -I_{B2} = 0.5A$			3	μs
		for BUV46/FI			0.8	μs
t_{on} t_s t_f	Turn-on Time Storage Time Fall Time	$I_C = 2A$ $V_{CC} = 150V$			1	μs
		$I_{B1} = -I_{B2} = 0.4A$			3	μs
		for BUV46A/AFI			0.8	μs

* Pulsed : pulse duration = 300 μs , duty cycle = 1.5%